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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/821,627		04/09/2004	Carlos Angulo Barrios	1153.087US1	8932	
21186	7590	06/17/2005		EXAMINER		
	•	NDBERG, WOES	PAK, SUNG H			
P.O. BOX 2 MINNEAPO		55402-0938	ART UNIT	PAPER NUMBER		
	,			2874		

DATE MAILED: 06/17/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application	No.	Applicant(s)	71-6
		10/821,627		BARRIOS ET AL.	
Office A	Action Summary	Examiner	·	Art Unit	
		Sung H. Pa		2874	
The MAILIN Period for Reply	G DATE of this communication ap	pears on the d	cover sheet with the c	orrespondence ad	dress
THE MAILING DA  - Extensions of time may after SIX (6) MONTHS (  - If the period for reply sp - If NO period for reply is - Failure to reply within the Any reply received by the	TATUTORY PERIOD FOR REPL TE OF THIS COMMUNICATION. be available under the provisions of 37 CFR 1.1 rom the mailing date of this communication. ecified above is less than thirty (30) days, a repl specified above, the maximum statutory period e set or extended period for reply will, by statute e Office later than three months after the mailin stment. See 37 CFR 1.704(b).	136(a). In no event ly within the statuto will apply and will e, cause the applic	t, however, may a reply be time by minimum of thirty (30) days expire SIX (6) MONTHS from the ation to become ABANDONED	ely filed will be considered timely the mailing date of this co	/. mmunication.
Status					
1) Responsive	to communication(s) filed on	·			
2a) This action is	s FINAL. 2b)⊠ This	s action is no	n-final:		
3)☐ Since this ap	plication is in condition for allowa	ance except fo	or formal matters, pro	secution as to the	merits is
closed in acc	cordance with the practice under t	Ex parte Qua	yle, 1935 C.D. 11, 45	3 O.G. 213.	
Disposition of Claims	3				
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Application Papers					
•	tion is objected to by the Examine	-			
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Priority under 35 U.S	-				
a) All b) 1. Certifi 2. Certifi 3. Copie applic	nent is made of a claim for foreign Some * c) None of: ed copies of the priority document documents of the certified copies of the priority document at the certified copies of the priority from the International Bureat detailed Office action for a list	its have been its have been prity documer au (PCT Rule	received. received in Application ats have been received 17.2(a)).	on No ed in this National	Stage
Attachment(s)					
1) Notice of References		•	1) Interview Summary		
	n's Patent Drawing Review (PTO-948) e Statement(s) (PTO-1449 or PTO/SB/08) e	,	Paper No(s)/Mail Da  5) Notice of Informal P  6) Other:		D-152)

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#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 3-7, 10, 15, 17-20 are rejected under 35 U.S.C. 102(e) as being anticipated by Liu (US 6,788,727 B2).

Liu discloses an optical device with all the limitations set forth in the claims, including: an electro-optic modulator (column 5 lines 19-23) comprising: a substrate (Fig. 8); a planar micro-cavity supported by the substrate (817- Fig. 8); a first Bragg reflector on a first side of the micro-cavity (815a- Fig. 8); a second Bragg reflector on a second side of the micro-cavity (815b- Fig. 8); a modulator that modulates a refractive index of the cavity (column 4 lines 45-50);

wherein the Bragg reflectors are distributed Bragg reflectors, comprising alternating areas having high and low refractive indcies (column 6 lines 51- column 7 lines 23);

wherein the device further comprises a rib extending throughthe cavity and Bragg reflectors (Fig. 4, column 7 lines 24-46);

wherein the device further comprises a lateral trench in the micro-cavity on both sides of the modulator (Fig. 7, column 9 lines 41-52);

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wherein the device further comprises an insulative layer fourmed on the substrate between the substrate and the micro-cavity and Bragg reflectors (809- Fig. 8).

Claims 1-21 are rejected under 35 U.S.C. 102(b) as being anticipated by Onischenko (WO 02/079863 A2).

Onischenko discloses an optical device with all the limitations set forth in the claims, including: a silicon substrate (Fig. 1, page 5, line 19); an insulator formed on the silicon substrate (page 5 line 19); a planar micro-cavity formed on the insulator (Fabry-Perot cavity: page 6 lines 23-25); a first Bragg reflector formed on a first side of the micro-cavity (Fig. 3); a second Bragg reflector formed on a second side of the micro-cavity (Fig. 3); a rib extending through the cavity and Bragg reflectors (Fig. 8-9); a PIN diode formed on the micro-cavity that modulates a refractive index of the cavity (page 10 lines 19-24); a lateral trench in the micro-cavity on both sides of the modulator (page 5 line 19- page 7 line 6);

wherein the distributed Bragg reflectors comprise alternating area having high and low refractive indices, wherein the high refractive index sections are formed of Si (silicon), and the low refractive index sections are formed of SiO<sub>2</sub> (silica) (page 5 lines 19-24);

wherein the device further comprising insulative layer formed on the substrate between the substrate and the micro-cavity and Bragg reflectors (83- Fig. 8).

### Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 2, 9, 11-14, 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Liu (US 6,788,727 B2) in view of Uomi et al (US 5,132,981).

Liu discloses an optical device with limitations set forth in the claims as discussed above, except it does not explicitly teach the use of PIN diode that modulates refractive index of the cavity.

On the other hand, the use of PIN diode for modulating refractive index of the optical modulator material is known in the art, for example, taught by Uomi (column 11 lines 24-56). The use of PIN diodes are well known to be advantageous and desirable in the art because it allows for fast, and reliable optical modulation with relatively low power consumption. Therefore, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to modify the device of Liu to use PIN diode as taught by Uomi.

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### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Sung H. Pak whose telephone number is (571) 272-2353. The examiner can normally be reached on Monday- Friday, 9AM-5PM.

The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Sung H. Pak Patent Examiner Art Unit 2874